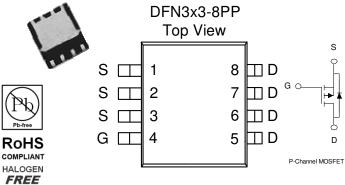
P-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r _{DS(on)} provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V _{DS} (V)	$I_{D}(A)$			
-20	$14 @ V_{GS} = -4.5V$	-13		
-20	19 @ $V_{GS} = -2.5V$	-12		



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			-20	V	
Gate-Source Voltage	V_{GS}	±8	V		
	$T_A=25^{\circ}C$] T_	-13		
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-11	A	
Pulsed Drain Current ^b	I_{DM}	±50			
Continuous Source Current (Diode Conduction) ^a	I_S	-2.1	A		
D. D a	$T_A=25^{\circ}C$	D	3.5	\mathbf{w}	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	rD	2.0	VV	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
a	t <= 10 sec	$R_{ heta JA}$	35	°C/W		
Maximum Junction-to-Ambient ^a	Steady State		81	°C/W		

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Downwater	Cymphel	T1 O 1111	Limits			
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250 \text{ uA}$	-1			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 8 V$			±100	nA
Zero Gate Voltage Drain Current	I _{DSS} _	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-1 -5	uA
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-50			Α
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -11.5 \text{ A}$ $V_{GS} = -2.5 \text{ V}, I_D = -9.3 \text{ A}$			14 19	mΩ
Forward Tranconductance ^A	g _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -11.5 \text{ A}$		29		S
Diode Forward Voltage	$V_{\sf SD}$	$I_S = 2.5 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V
Dynamic ^b					•	•
Total Gate Charge	Q_g			25		
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -11.5 \text{ A}$		11		nC
Gate-Drain Charge	Q_{gd}	ID = -11.5 A		17		
Input Capacitance	C _{iss}			2300		
Output Capacitance	C _{oss}	V_{DS} =-15V, V_{GS} =0V, f=1MHz		600		рF
Reverse Transfer Capacitance	C_{rss}			300		
Turn-On Delay Time	t _{d(on)}			15		
Rise Time	t _r	$V_{DD} = \text{-15 V}, \; R_L = 6 \; \Omega \;\;,$		13		nS
Turn-Off Delay Time	$t_{d(off)}$	$I_D = -1 A, V_{GEN} = -10 V$		100		
Fall-Time	t _f			54		

Notes

a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics (P-Channel)

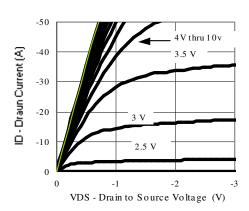


Figure 1. On-Region Characteristics

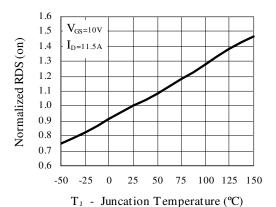


Figure 3. On-Resistance Variation with Temperature

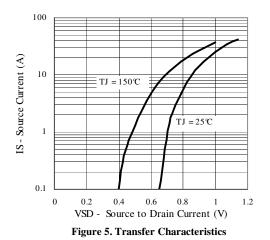


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

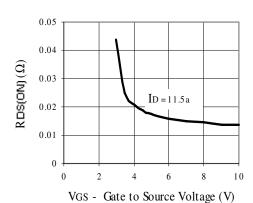


Figure 4. On-Resistance with Gate to Source Voltage

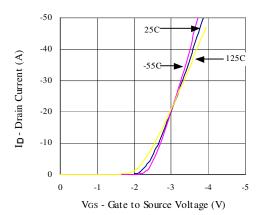


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

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Typical Electrical Characteristics (P-Channel)

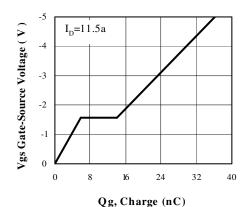


Figure 7. Gate Charge Characteristics

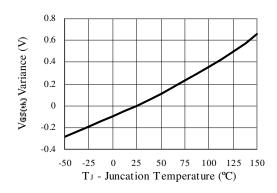


Figure 9. Maximum Safe Operating Area

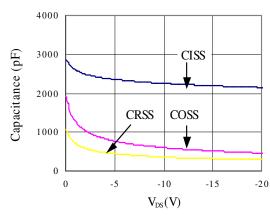


Figure 8. Capacitance Characteristics

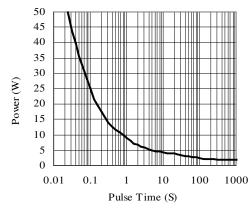


Figure 10. Single Pulse Maximum Power Dissipation

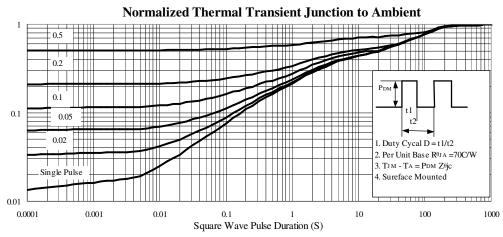
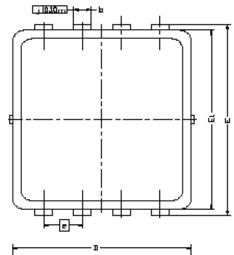
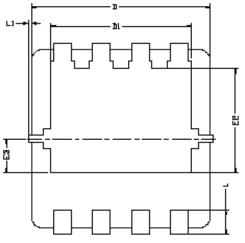
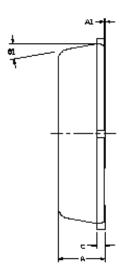


Figure 11. Transient Thermal Response Curve

Package Information







DIM.	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	0,700	0'80	0.900	0.0276	0.0315	0.0354
A1	0.00		0.05	0.000		0.002
b	0.24	0.30	0.35	0.009	0.012	0.014
2	0.10	0.152	0.25	0,004	0,006	0.010
ם	3.00 BSC			0	118 BS	C
D1	2.35 BCC			a.	093 BS	C 2
Ε	3,20 BSC			0,	126 BS	S.
E1	3.00 BSC			٥	.118 BS	:C
E5	1.75 BSC			a.	069 BS	ic o
E3	0.575 BSC			0.	023 BS	3C
6	0.65 BSC			Ō.	026 BS	C 2
Г	0,30	0,40	0,50	0,0118	0.0157	0.0197
L1			0.100	D		0.004
9 1	٥٥	10*	12*	0*	10*	12*